

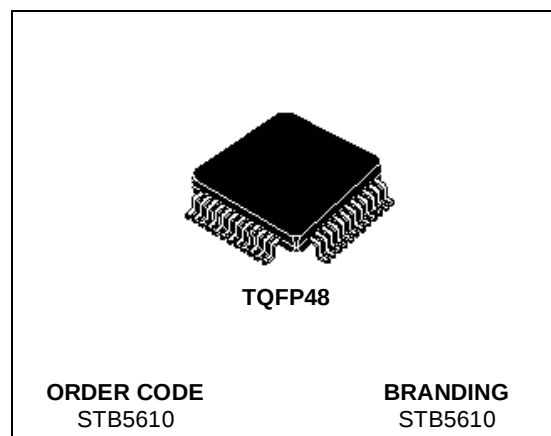


STB5610

GPS RF FRONT-END IC

PRELIMINARY DATA

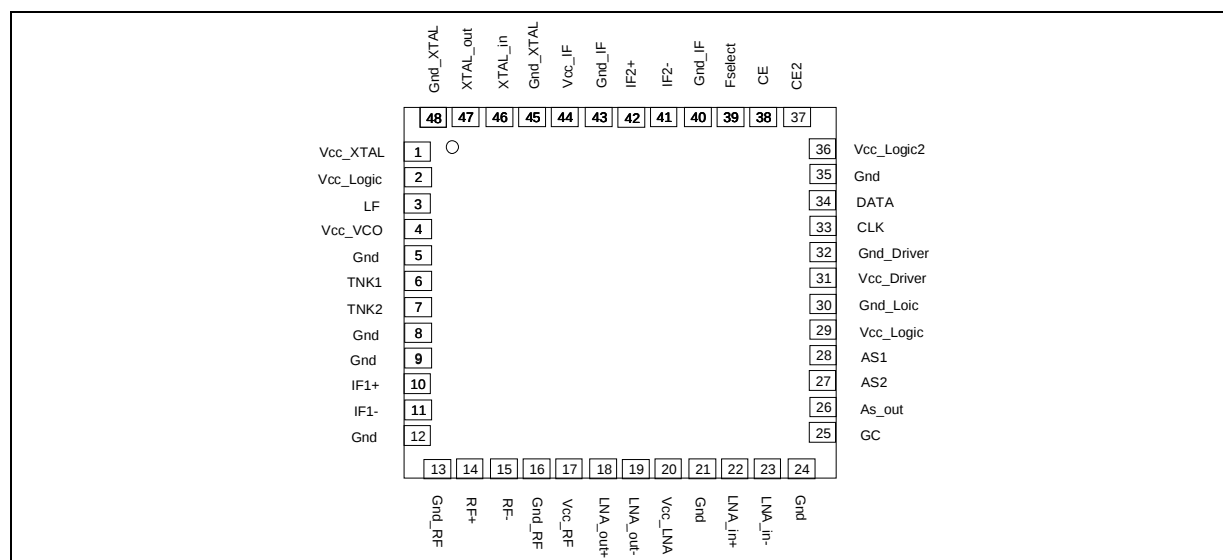
- ONE CHIP SYSTEM TO INTERFACE GPS ANTENNA TO GPS MICRO CONTROLLER
- ABLE TO SUPPORT ACTIVE AND PASSIVE ANTENNA
- MINIMUM EXTERNAL COMPONENTS
- COMPATIBLE WITH GPS L1 SPS SIGNAL AND GALILEO FREQUENCIES
- CMOS OUTPUT LEVELS
- 2.7 V .. 3.6 V SUPPLY VOLTAGE
- EMBEDDED LOW PHASE NOISE PLL
- ACTIVE ANTENNA SENSOR
- SMART CHIP ENABLE FUNCTION FOR POWER CONSUMPTION OPTIMIZATION
- ESD PROTECTED



DESCRIPTION

The STB5610, using ST Microelectronics RF Bipolar technology, implements a Global Positioning System RF front-end. The chip provides down conversion from the 1575.42 MHz GPS (L1) signal to 4.092 MHz Output signal. The integrated PLL with on-chip reference oscillator uses a low cost 16.368 MHz crystal. No TCXO is required.

PIN CONNECTION



December, 15 2003

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STB5610**PIN CONFIGURATION**

PIN	Symbol	Typ. DC Bias	Description	External Circuit
1	Vcc_XTAL		Power supply	
2	Vcc_Logic		Power supply	
3	LF		Loop filter	
4	Vcc_VCO		Power supply	
5	Gnd		Ground	
6	TNK1		Tank Input	
7	TNK2		Tank Input	
8	Gnd		Ground	
9	Gnd		Ground	
10	IF1+		Mixer Output	
11	IF1-		Mixer Output	
12	Gnd		Ground	
13	Gnd_RF		Ground	
14	RF+		RF amp. input	
15	RF-		RF amp. input	
16	Gnd_RF		Ground	
17	Vcc_RF		Power supply	
18	LNA_Out+		LNA output	
19	LNA_Out-		LNA output	
20	Vcc_LNA		Power supply	
21	Gnd_LNA		Ground	
22	LNA_in+		LNA input	
23	LNA_in-		LNA input	
24	Gnd_LNA		Ground	

PIN CONFIGURATION

PIN	Symbol	Typ. DC Bias	Description	External Circuit
25	GC		LNA Gain control	
26	AS_Out		Antenna sensor output	
27	AS2		Antenna sensor input	
28	AS1		Vcc Antenna Supply	
29	Vcc_Logic		Power supply	
30	Gnd_Logic		Ground	
31	Vcc_Driver		Supply Voltage	
32	Gnd_Driver		Ground	
33	CLK		Clock	
34	DATA		Data	
35	Gnd		Ground	
36	Vcc_Logic2		Supply Voltage	
37	CE2		Chip Enable (no data)	
38	CE		Chip Enable	
39	Fselect		Frequency Selector	
40	Gnd_IF		Ground	
41	IF2-		Lim. Amp. Output	
42	IF2+		Lim. Amp. Output	
43	Gnd_IF		Ground	
44	Vcc_IF		Supply Voltage	
45	Gnd_XTAL		Ground	
46	XTAL_in		Crystal Input	
47	XTAL_out		Crystal Output	
48	Gnd_XTAL		Ground	

ABSOLUTE MAXIMUM RATING

Symbol	Parameter	Value	Unit
V _{cc}	Supply voltage	5.9	V
T _j	Junction operating temperature	-40 to 125	°C

THERMAL DATA

Symbol	Parameter	Value	Unit
R _{thj-case}	Thermal resistance junction-case	TBD	°C/W

ELECTRICAL CHARACTERISTICS (V_{cc} = 3+/-10%, T_{case}= 25 °C)

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
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SUPPLY

V _{cc}	Supply voltage		2.7	3.3	3.6	V
I _{cc}	Supply current			37		mA
AS1	V _{cc} Antenna Supply		2.7	3.3 / 5	5.5	V

LNA

G _p	Power gain	Pin GC at GND Pin GC at V _{cc}		19 10		dB
NF	Noise figure	Pin GC at GND Pin GC at V _{cc}		3 10		dB
IIP3	Input IP3	Pin GC at GND Pin GC at V _{cc}		-20 -5		dBm
VSWR _{in}	Voltage Stat. Wave Ratio	Z _L =50Ω			2.1	

RF AMPLIFIER AND MIXER CHAIN

IIP3	Input IP3			-19		dBm
NF	Noise Figure			5.5		dB
Z _{IN}	Input impedance			50		Ω
Z _{OUT}	Differential output impedance			1.4		KΩ
f _{RF}	Input signal RF			1.575		MHz
G	Voltage Conversion Gain			30		dB

FIRST LIMITING AMPLIFIER

G	Voltage Gain			60		dB
Z _{OUT}	Differential output impedance			2.4		KΩ

STB5610**ELECTRICAL CHARACTERISTICS (Vcc = 3+/-10%, Tcase= 25 °C)**

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
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SECOND LIMITING AMPLIFIER

G	Voltage Gain			30		dB
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VCO (GPS LO frequency 1555MHz)

VCO	Phase noise	$\Delta f = 1\text{KHz}$, SSB (10KHz PLL closed loop bandwidth)		-60		dBc/Hz
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OUTPUT BUFFER (square wave CMOS level)

V _{OH}	High output voltage		V _{cc} -0.4		V _{cc}	V
V _{OL}	Low output voltage		0		0+0.4	V

PHASE LOCKED LOOP

XTAL	Reference crystal			16.368		MHz
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INPUT CONTROL PINS TABLE (The logic levels are TTL compatible)**GC Pin (Ina gain control pin)**

Logic level	Value
Low	Max Gain
High	Min Gain

CE Pin (Total chip enable pin)

Logic level	Value
Low	Switch-off
High	Switch-on

CE2 Pin (Analog portion enable pin)

Logic level	Value
Low	Switch-off
High	Switch-on

FSELECT (Frequencies Selector Pin)

Logic level	Value
Low	GPS frequency
High	Galileo frequency

OUTPUT CONTROL PINS TABLE

The Asout pin output provides information on Antenna current consumption

ASout Pin (Antenna sensor pin)*

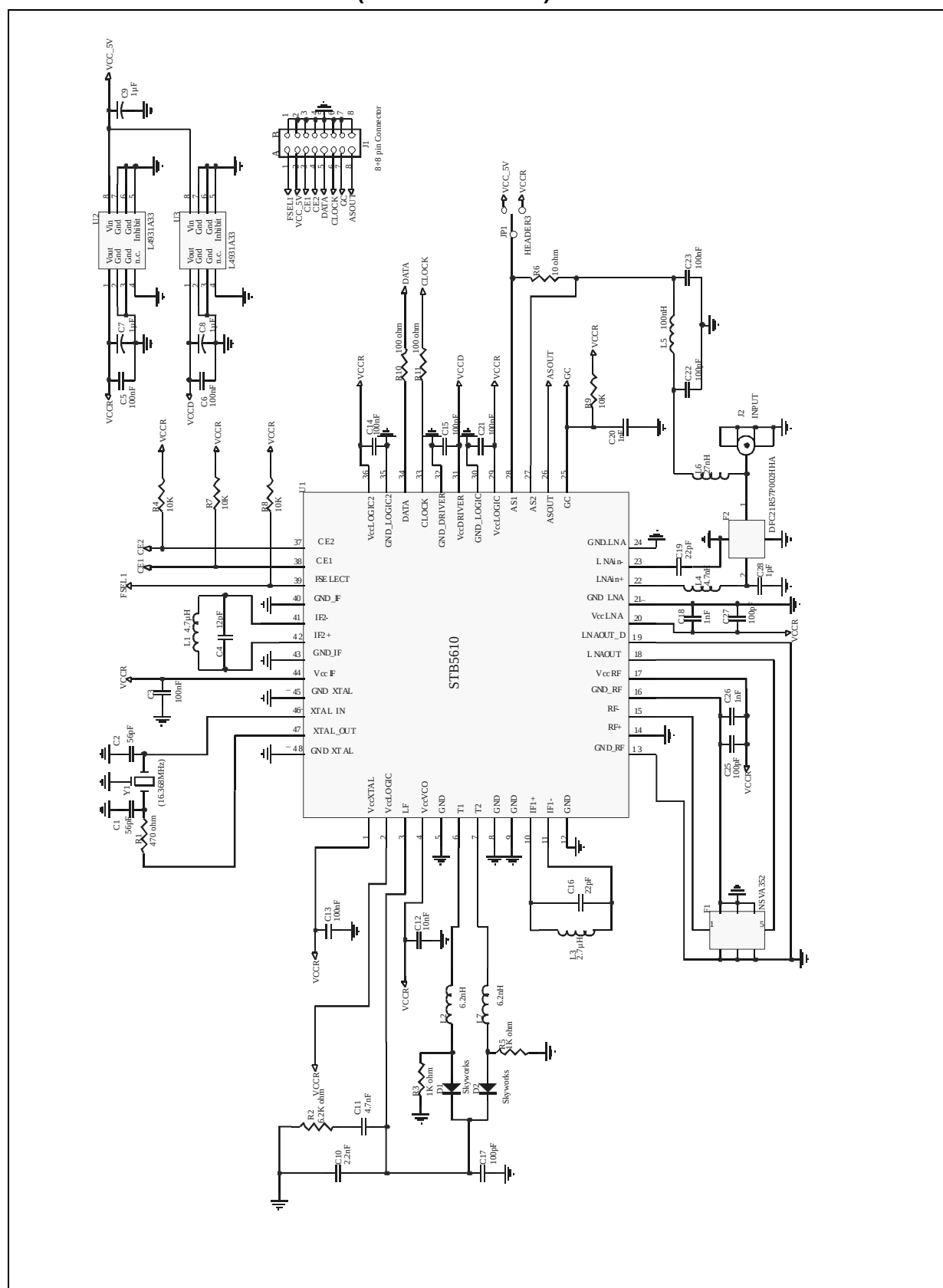
Logic level	Value
Low**	I _{ant} <10mA I _{ant} >40mA
High**	10mA<I _{ant} <40mA

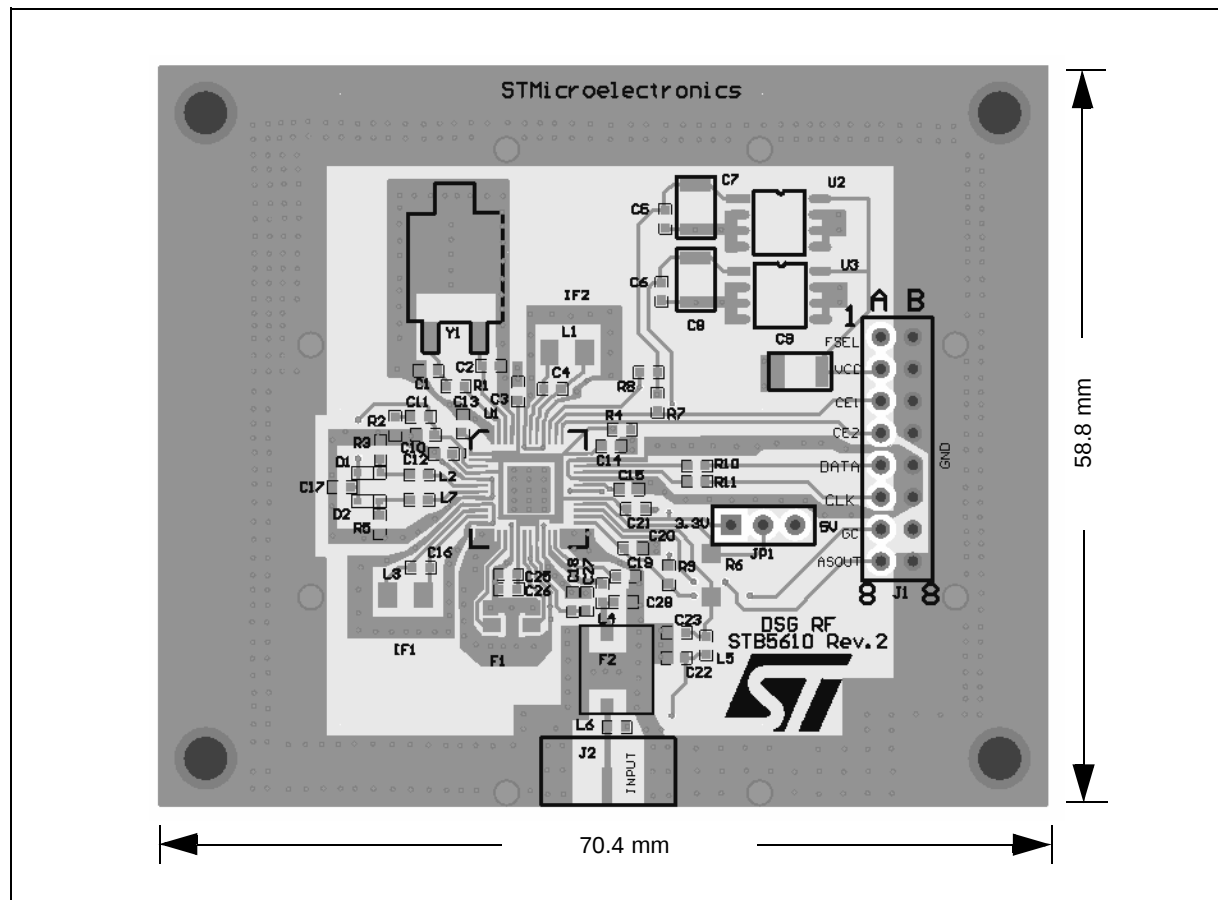
* It is referred to external sensing resistor of 10 OHm

Application requiring higher or lower current threshold should adjust the resistor value appropriately

** The logic levels are referred to STB5610 Supply Voltage

APPLICATION BOARD SCHEMATIC (ACTIVE ANTENNA)



STB5610**APPLICATION BOARD LAYOUT (ACTIVE ANTENNA)**

BILL OF MATERIALS

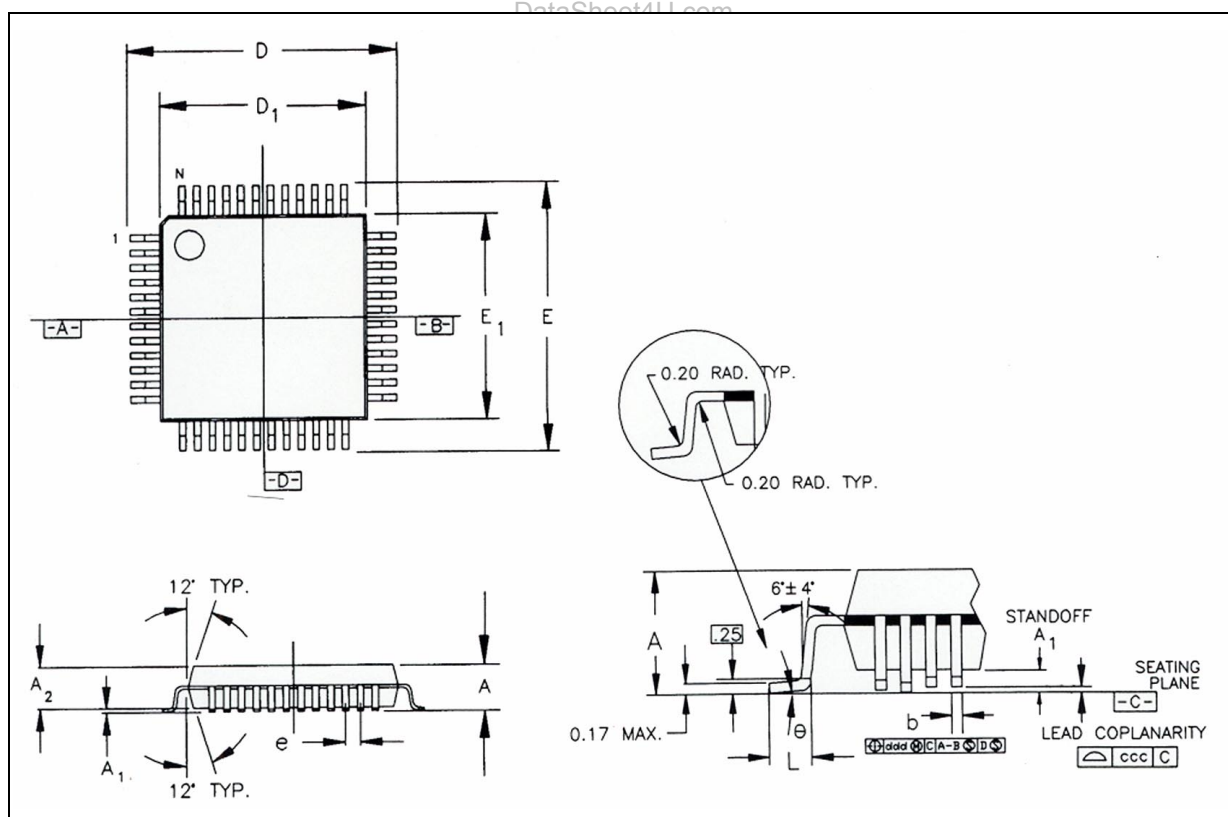
Q.ty	Reference Designator	Value	Manufacturer
1	R1	470 ohm	NEOHM (0603)
1	R2	6.2K ohm	NEOHM (0603)
2	R3, R5	1K ohm	NEOHM (0603)
1	R6	10 ohm	NEOHM (0603)
4	R4,R7,R8,R9	10K ohm	NEOHM (0603)
2	R10,R11	100 ohm	NEOHM (0603)
2	C1,C2	56pF	Murata (series GRM18)
1	C4	12pF	Murata (series GRM18)
3	C7, C8, C9	1μF (electrolytic)	Kemet (series T491) Case A
1	C10	2.2nF	Murata (series GRM18)
1	C11	4.7nF	Murata (series GRM18)
1	C12	10nF	Murata (series GRM18)
4	C16,C19	22pF	Murata (series GRM18)
7	C3,C5, C6,C13,C14,C21,C23	100nF	Murata (series GRM18)
3	C18, C20,C26	1nF	Murata (series GRM18)
5	C15,C17,C22,C25,C27	100pF	Murata (series GRM18)
1	C28	1.8pF	Murata (series GRM18)
1	L1	4.7μH	Coilcraft (series 1008CS)
1	L2	6.2nH	Murata (series LQP18M)
1	L3	2.7μH	Coilcraft (series 1008CS)
1	L4	4.7nH	Murata (series LQP18M)
1	L5	100nH	Murata (series LQW18)
1	L6	27nH	Murata (series LQP18M)
1	L7	6.2nH	Murata (series LQP18M)
1	U1	STB5610	ST
2	U2, U3	L4931ABD33	ST
1	J1	8+8 pin Connector	Various
1	J2	SMA Connector (female)	Johnson
1	F1	NSVA352	NJR Corporation
1	F2	DFC21R57P002HHA ⁽¹⁾	Murata
1	D1	SMV1405-079	Skyworks
1	D2	SMV1405-079	Skyworks
1	Y1	DHF32UM-1SJ(16.368MHz)	Rakon

⁽¹⁾ This Part Number will be changed in DFCB21G57LDJAB-TT1 by MURATA

STB5610**MECHANICAL DATA**

DIM.	mm		
	MIN.	TYP.	MAX
A			1.60
A1	0.05		0.15
A2	1.35	1.40	1.45
D	8.75	9.00	9.25
D1	6.9	7.00	7.1
E	8.75	9.00	9.25
E1	6.9	7.00	7.1
L	0.5	0.60	0.75
e		0.5	
b	0.17	0.22	0.27
ccc			0.08
ddd			0.08
TETA	0°		7°

Note: L is measured at gage plane (at 0.25 above the seating plane)



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